# 0.75-Ω DUAL SPST ANALOG SWITCH WITH 1.8-V COMPATIBLE INPUT LOGIC

### **FEATURES**

- **Dual Single-Pole Single-Throw (SPST) Switch**
- 1.65-V to 5.5-V Power Supply (V<sub>+</sub>)
- Isolation in Powerdown Mode,  $V_{\perp} = 0$
- Low ON-State Resistance (0.75  $\Omega$  Typ)
- **Excellent ON-State Resistance Matching**
- Low Charge Injection
- **Low Total Harmonic Distortion (THD)**
- High Bandwidth (260 MHz)
- 1.8-V Compatible Control Input Threshold Independent of V<sub>+</sub>
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II

**ESD Performance Tested Per JESD 22** 

- 2000-V Human-Body Model (A114-B, Class II)
- 1000-V Charged-Device Model (C101)

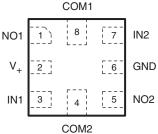
### APPLICATIONS

- **Cell Phones**
- **PDAs**
- Portable Instrumentation
- Audio and Video Signal Routing
- **Portable Media Players**
- **Communication Circuits**
- **Computer Peripherals**

### (TOP VIEW) NO<sub>1</sub> 8 V<sub>+</sub> COM1 2 7 IN1 6 COM2 IN<sub>2</sub> 3 GND 4 5 NO2

**DCU PACKAGE** 

### **RSE PACKAGE** (TOP VIEW) COM<sub>1</sub>



### **DESCRIPTION**

The TS5A21366 is a dual single-pole single-throw (SPST) analog switch that is designed to operate from 1.65 V to 5.5 V. The device offers a low ON-state resistance and an excellent channel-to-channel ON-state resistance matching. The device has excellent total harmonic distortion (THD) performance and consumes very low power.

The control pin can be connected to a low voltage GPIO allowing it to be controlled by 1.8-V signals.

These features make this device ideal for portable audio applications.

The TS5A21366 is available in a small, space-saving 8-pin DCU or RSE package and is characterized for operation over the free-air temperature range of -40°C to 85°C.

### ORDERING INFORMATION(1)

T <sub>A</sub>	PACK	AGE <sup>(2)</sup>	ORDERABLE PART NUMBER	TOP-SIDE MARKING
–40°C to 85°C	VSSOP - DCU	Tape and reel	TS5A21366DCUR	JBS_
-40 C to 65 C	QFN - RSE	Tape and reel	TS5A21366RSER	4F

For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.



### SUMMARY OF CHARACTERISTICS(1)

Configuration	Single-pole, single-throw (SPST)
Number of channels	2
ON-state resistance (r <sub>ON</sub> )	0.75 Ω
ON-state resistance match (Δr <sub>ON</sub> )	0.04 Ω
ON-state resistance flatness (r <sub>ON(flat)</sub> )	0.15 Ω
Turn-on/turn-off time (t <sub>ON</sub> /t <sub>OFF</sub> )	49 ns/243 ns
Charge injection (Q <sub>C</sub> )	1.3 pC
Bandwidth (BW)	260 MHz
OFF isolation (O <sub>ISO</sub> )	–62 dB at 1 MHz
Crosstalk (X <sub>TALK</sub> )	–98 dB at 1 MHz
Total harmonic distortion (THD)	0.002%
Power-supply current (I <sub>+</sub> ) with V <sub>IN</sub> = 1.8 V	7.6 μΑ
Package option	8-pin QFN (RSE) or VSSOP (DCU)

(1)  $V_+ = 5 V$ ,  $T_A = 25$ °C

### **FUNCTION TABLE**

IN	NO TO COM, COM TO NO
L	OFF
Н	ON

### **TERMINAL FUNCTIONS**

	TERMINAL		
DCU PIN NO.	RSE PIN NO.	NAME	DESCRIPTION
1	1	NO1	Switch 1, normally open
2	8	COM1	Switch 1, common
3	7	IN2	Switch 2, digital control pin to connect COM to NO
4	6	GND	Digital ground
5	5	NO2	Switch 2, normally open
6	4	COM2	Switch 2, common
7	3	IN1	Switch 1, digital control pin to connect COM to NO
8	2	V <sub>+</sub>	Power supply

### ABSOLUTE MAXIMUM RATINGS(1)(2)

over operating free-air temperature range (unless otherwise noted)

			MI	N MAX	UNIT
V <sub>+</sub>	Supply voltage range <sup>(3)</sup>		-0	.5 6.5	V
$V_{NO} \ V_{COM}$	DM Tallage Tallage		-0	.5 V <sub>+</sub> + 0.5	V
I <sub>K</sub>	Analog port diode current	$V_{NO}, V_{COM} < 0$		50	mA
I <sub>NO</sub>			-20	00 200	mA
	ON-state peak switch current <sup>(6)</sup>	$v_{NO}$ , $v_{COM} = 0$ to $v_+$	-40	00 400	IIIA
VI	Digital input voltage range (3)(4)		-0	.5 6.5	V
I <sub>IK</sub>	Digital input clamp current	V <sub>I</sub> < 0	_t	50	mA
I <sub>+</sub>	Continuous current through V <sub>+</sub>			100	mA
I <sub>GND</sub>	Continuous current through GND		-10	00 100	mA
T <sub>stg</sub>	Storage temperature range		-6	55 150	°C

<sup>(1)</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- (2) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum
- (3) All voltages are with respect to ground, unless otherwise specified.
- (4) The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- (5) This value is limited to 5.5 V maximum.
- (6) Pulse at 1-ms duration <10% duty cycle

### THERMAL IMPEDANCE

				UNIT
0	Dockers thermal impedance (1)	DCU package	227	°C/W
θJA	θ <sub>JA</sub> Package thermal impedance <sup>(1)</sup>	RSE package	253	\ C/VV

<sup>(1)</sup> The package thermal impedance is calculated in accordance with JESD 51-7.

### RECOMMENDED OPERATING CONDITIONS

over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
V <sub>+</sub>	Power supply voltage range <sup>(1)</sup>	1.65	5.5	V
$V_{NO} \ V_{COM}$	Analog signal voltage range	0	$V_{+}$	V
$V_{IN}$	Control input voltage range	0	5.5	V
T <sub>A</sub>	Ambient temperature	-40	85	°C

(1) V<sub>+</sub> needs to be supplied prior to the control input, refer to the Application Information section.

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### **ELECTRICAL CHARACTERISTICS FOR 5-V SUPPLY<sup>(1)</sup>**

 $\mbox{V}_{+} = 4.5 \mbox{ V}$  to 5.5 V,  $\mbox{T}_{\mbox{\scriptsize A}} = -40\mbox{\ensuremath{^{\circ}}}\mbox{C}$  to 85\ensuremath{^{\circ}}\mbox{C} (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDIT	TIONS	$T_A$	V <sub>+</sub>	MIN	TYP	MAX	UNIT		
Analog Switch											
Analog signal range	$V_{COM}, V_{NO}$					0		V <sub>+</sub>	V		
ON-state resistance	r <sub>on</sub>	$V_{NO} = 2.5 \text{ V},$ $I_{COM} = -100 \text{ mA},$	Switch ON, See Figure 15	25°C Full	4.5 V		0.75	1.4	Ω		
ON-state resistance		.,	0 11 1 011	25°C			0.04	0.1			
match between channels	$\Delta r_{ m on}$	$V_{NO} = 2.5 \text{ V},$ $I_{COM} = -100 \text{ mA},$	Switch ON, See Figure 15	Full	4.5 V			0.1	Ω		
ON-state resistance	_	V <sub>NO</sub> = 1 V, 1.5 V, 2.5 V,	Switch ON,	25°C	4.5 V		0.15	0.25	Ω		
flatness	r <sub>on(flat)</sub>	$I_{COM} = -100 \text{ mA},$	See Figure 15	Full	4.5 V			0.25	12		
		V <sub>NO</sub> = 1 V,				-10	1.4	10			
NO OFF leakage current	I <sub>NO(OFF)</sub>	$V_{COM} = 4.5 \text{ V},$ or $V_{NO} = 4.5 \text{ V},$ $V_{COM} = 1 \text{ V},$	Switch OFF, See Figure 16	Switch OFF,	Switch OFF,	25°C	5.5 V	-235		235	nA
	,   V <sub>N</sub>	$V_{NO} = 0 \text{ to } 5.5 \text{ V},$		Full	0 V	<b>-</b> 5	0.06	5	μΑ		
	I <sub>NO(PWROFF)</sub>	$V_{COM} = 5.5 \text{ V to 0},$		Full	UV	-10		10	μΑ		
COM OFF leakage current		V <sub>COM</sub> = 1 V,		25°C		-10	1.4	10			
	$I_{COM(OFF)}$ $V_{NO} = 4.5 \text{ V},$ or $V_{COM} = 4.5 \text{ V},$ $V_{NO} = 1 \text{ V},$	Switch OFF, See Figure 16	Full	5.5 V	-235		235	nA			
		$V_{NO} = 0 \text{ to } 5.5 \text{ V},$		25°C	0.17	-5	0.06	5	۸		
	ICOM(PWROFF)	$V_{COM} = 5.5 \text{ V to } 0,$		Full	0 V	-10		10	μΑ		
		$V_{NO} = 1 V$ ,	11	25°C		-5	1.33	5			
NO ON leakage current	I <sub>NO(ON)</sub>	$V_{COM} = Open,$ or $V_{NO} = 4.5 \text{ V},$ $V_{COM} = Open,$	Switch ON, See Figure 17	Full	5.5 V	-50		50	nA		
		$V_{COM} = 1 V$ ,		25°C		<b>-</b> 5	1.33	5			
COM ON leakage current	I <sub>COM(ON)</sub>	$V_{NO}$ = Open, or $V_{COM}$ = 4.5 V, $V_{NO}$ = Open,	Switch ON, See Figure 17	Full	5.5 V	-50		50	nA		
Digital Control Inputs	(IN1, IN2) <sup>(2)</sup>	•		•							
Input logic high	V <sub>IH</sub>			Full	5.5 V	1.05		5.5	V		
Input logic low	V <sub>IL</sub>			Full	5.5 V	0		0.6	V		
Input leakage current	I <sub>IH</sub> , I <sub>IL</sub>	V <sub>I</sub> = 1.95 V or GND		Full	5.5 V	-0.6		0.6	μΑ		
Input resistance	r <sub>IN</sub>	V <sub>I</sub> = 1.95 V		Full	5.5 V		6		MΩ		

<sup>(1)</sup> The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum

<sup>(2)</sup> All unused digital inputs of the device must be held at V<sub>+</sub> or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

### **ELECTRICAL CHARACTERISTICS FOR 5-V SUPPLY (continued)**

 $V_{+} = 4.5 \text{ V to } 5.5 \text{ V}, T_{A} = -40 ^{\circ}\text{C} \text{ to } 85 ^{\circ}\text{C} \text{ (unless otherwise noted)}$ 

PARAMETER	SYMBOL	TEST CONI	DITIONS	TA	V <sub>+</sub>	MIN	TYP	MAX	UNIT
Dynamic	T.	<del>-  </del>		1				l	
				25°C	5 V	39	49	72	
Turn-on time	t <sub>ON</sub>	$V_{COM} = V_+,$ $R_L = 50 \Omega,$	C <sub>L</sub> = 35 pF, See Figure 19	Full	4.5 V to 5.5 V	28		97	ns
		V V	0 25 - 5	25°C	5 V	168	243	318	
Turn-off time	t <sub>OFF</sub>	$V_{COM} = V_+,$ $R_L = 50 \Omega,$	$C_L = 35 \text{ pF},$ See Figure 19	Full	4.5 V 5.5 V	178		323	ns
Charge injection	Q <sub>C</sub>	$V_{GEN} = 0,$ $R_{GEN} = 0,$	C <sub>L</sub> = 1 nF, See Figure 23	25°C	5 V		1.3		рС
NO OFF capacitance	C <sub>NO(OFF)</sub>	V <sub>NO</sub> = V <sub>+</sub> or GND, Switch OFF,	See Figure 18	25°C	5 V		19		pF
COM OFF capacitance	C <sub>COM(OFF)</sub>	V <sub>NO</sub> = V <sub>+</sub> or GND, Switch OFF,	See Figure 18	25°C	5 V		17		pF
NO ON capacitance	C <sub>NO(ON)</sub>	V <sub>NO</sub> = V <sub>+</sub> or GND, Switch ON,	See Figure 18	25°C	5 V		33		pF
COM ON capacitance	C <sub>COM(ON)</sub>	V <sub>COM</sub> = V <sub>+</sub> or GND, Switch ON,	See Figure 18	25°C	5 V		33		pF
Digital input capacitance	Cı	$V_I = V_+ \text{ or GND},$	See Figure 18	25°C	5 V		2.5		pF
Power supply rejection ratio	PSRR	$ f = 10 \text{ kHz}, \\ V_{COM} = 1 \text{ Vrms}, \\ R_L = 50 \ \Omega, $	C <sub>L</sub> = 15 pF, See Figure 25	25°C	5 V		-84		dB
Bandwidth	BW	$R_L = 50 \Omega$ , Switch ON,	See Figure 20	25°C	5 V		260		MHz
OFF isolation	O <sub>ISO</sub>	$R_L = 50 \Omega$ , $f = 1 MHz$ ,	Switch OFF, See Figure 21	25°C	5 V		-62		dB
Crosstalk	X <sub>TALK</sub>	$R_L = 50 \Omega$ , $f = 1 MHz$ ,	Switch ON, See Figure 22	25°C	5 V		-98		dB
Total harmonic distortion	THD	$R_L = 600 \Omega,$ $C_L = 15 pF,$	f = 20 Hz to 20 kHz, See Figure 24	25°C	5 V		0.002		%
Supply								- '	
Positive supply current	I <sub>+</sub>	V <sub>I</sub> = 1.95 V or GND	Switch ON or OFF	25°C Full	5.5 V		7.6	9	μА

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### **ELECTRICAL CHARACTERISTICS FOR 3.3-V SUPPLY<sup>(1)</sup>**

 $V_{+} = 3 \text{ V}$  to 3.6 V,  $T_{A} = -40^{\circ}\text{C}$  to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONI	DITIONS	TA	V <sub>+</sub>	MIN	TYP	MAX	UNIT
Analog Switch									
Analog signal range	V <sub>COM</sub> , V <sub>NO</sub>					0		V <sub>+</sub>	V
ON-state resistance	r <sub>on</sub>	$V_{NO} = 2 V$ , $I_{COM} = -100 \text{ mA}$ ,	Switch ON, See Figure 15	25°C Full	3 V		1.1	1.5 1.8	Ω
ON-state resistance match between channels	Δr <sub>on</sub>	V <sub>NO</sub> = 2 V, 0.8 V I <sub>COM</sub> = -100 mA,	Switch ON, See Figure 15	25°C Full	3 V		0.045	0.1	Ω
ON-state resistance flatness	r <sub>on(flat)</sub>	$V_{NO} = 2 \text{ V}, 0.8 \text{ V},$ $I_{COM} = -100 \text{ mA},$	Switch ON, See Figure 15	25°C Full	3 V		0.15	0.25 0.25	Ω
NO OFF leakage current	I <sub>NO(OFF)</sub>	$V_{NO} = 1 \text{ V},$ $V_{COM} = 3 \text{ V}, 1 \text{ V},$ or $V_{NO} = 3 \text{ V},$ $V_{COM} = 1 \text{ V},$	Switch OFF, See Figure 16	25°C	3.6 V	-5 -160	0.9	160	nA
	I <sub>NO(PWROFF)</sub>	$V_{NO} = 0 \text{ to } 3.6 \text{ V},$ $V_{COM} = 3.6 \text{ V to } 0,$		Full	0 V	-5 -10	0.03	5 10	μΑ
COM OFF leakage current		$V_{NO} = 3 V$ ,		25°C	3.6 V	-5	0.9	5	nA
	e $I_{COM(OFF)}$ or $V_{NO} = 1$	$V_{COM} = 1 \text{ V},$ or $V_{NO} = 1 \text{ V},$ $V_{COM} = 3 \text{ V},$	Switch OFF, See Figure 16	Full		-160		160	
	1	$V_{NO} = 0 \text{ to } 3.6 \text{ V},$		25°C	0 V	<b>-</b> 5	0.03	5	^
	ICOM(PWROFF)	$V_{COM} = 3.6 \text{ V to 0},$		Full	UV	-10		10	μΑ
		$V_{NO} = 1 V$		25°C		-2	1	2	
NO ON leakage current	I <sub>NO(ON)</sub>	$V_{COM}$ = Open, or $V_{NO}$ = 3 V, $V_{COM}$ = Open,	Switch ON, See Figure 17	Full	3.6 V	-20		20	nA
		$V_{COM} = 1 V$ ,		25°C		-2	1	2	
COM ON leakage current	I <sub>COM(ON)</sub>	$V_{NO} = Open,$ or $V_{COM} = 3 \text{ V},$ $V_{NO} = Open,$	See Figure 17	Full	3.6 V	-20		20	nA
Digital Control Inputs	s (IN1, IN2) <sup>(2)</sup>			•				,	
Input logic high	V <sub>IH</sub>			Full	3.6 V	1.05		5.5	V
Input logic low	V <sub>IL</sub>			Full	3.6 V	0		0.6	V
Input leakage current	I <sub>IH</sub> , I <sub>IL</sub>	V <sub>I</sub> = 1.95 V or GND		Full	3.6 V	-0.6		0.6	μΑ
Input resistance	r <sub>IN</sub>	V <sub>I</sub> = 1.95 V		Full	3.6 V		6		МΩ

<sup>(1)</sup> The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum

<sup>(2)</sup> All unused digital inputs of the device must be held at V<sub>+</sub> or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

# **ELECTRICAL CHARACTERISTICS FOR 3.3-V SUPPLY (continued)**

 $V_{+} = 3 \text{ V}$  to 3.6 V,  $T_{A} = -40^{\circ}\text{C}$  to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONI	DITIONS	$T_A$	V <sub>+</sub>	MIN	TYP	MAX	UNIT
Dynamic	•			•				1	
		V V	C 25 x 5	25°C	3.3 V	66	83	133	
Turn-on time	t <sub>ON</sub>	$V_{COM} = V_+,$ $R_L = 50 \Omega,$	C <sub>L</sub> = 35 pF, See Figure 19	Full	3 V to 3.6 V	43		178	ns
		V - V	$C_{L} = 35 \text{ pF},$	25°C	3.3 V	138	247	306	
Turn-off time	t <sub>OFF</sub>	$V_{COM} = V_+,$ $R_L = 50 \Omega,$	See Figure 19	Full	3 V to 3.6 V	204		329	ns
Charge injection	Q <sub>C</sub>	$V_{GEN} = 0,$ $R_{GEN} = 0,$	C <sub>L</sub> = 1 nF, See Figure 23	25°C	3.3 V		1.3		рС
NO OFF capacitance	C <sub>NO(OFF)</sub>	$V_{NO} = V_{+}$ or GND, Switch OFF,	See Figure 18	25°C	3.3 V		19		pF
COM OFF capacitance	C <sub>COM(OFF)</sub>	V <sub>COM</sub> = V <sub>+</sub> or GND, Switch OFF,	See Figure 18	25°C	3.3 V		17		pF
NO ON capacitance	C <sub>NO(ON)</sub>	V <sub>NO</sub> = V <sub>+</sub> or GND, Switch ON,	See Figure 18	25°C	3.3 V		30		pF
COM ON capacitance	C <sub>COM(ON)</sub>	V <sub>COM</sub> = V <sub>+</sub> or GND, Switch ON,	See Figure 18	25°C	3.3 V		30		pF
Digital input capacitance	Cı	$V_I = V_+ \text{ or GND},$	See Figure 18	25°C	3.3 V		2.5		pF
Power supply rejection ratio	PSRR	$ f = 10 \text{ kHz}, \\ V_{COM} = 1 \text{ Vrms}, \\ R_L = 50 \ \Omega, $	C <sub>L</sub> = 15 pF, See Figure 25	25°C	3.3 V		-84		dB
Bandwidth	BW	$R_L = 50 \Omega$ , Switch ON,	See Figure 20	25°C	3.3 V		260		MHz
OFF isolation	O <sub>ISO</sub>	$R_L = 50 \Omega$ , $f = 1 MHz$ ,	Switch OFF, See Figure 21	25°C	3.3 V		-62		dB
Crosstalk	X <sub>TALK</sub>	$R_L = 50 \Omega$ , $f = 1 MHz$ ,	Switch ON, See Figure 22	25°C	3.3 V		-99		dB
Total harmonic distortion	THD	$R_L = 600 \Omega,$ $C_L = 15 \text{ pF},$	f = 20 Hz to 20 kHz, See Figure 24	25°C	3.3 V		0.004		%
Supply									
Positive supply	I <sub>+</sub>	V <sub>I</sub> = 1.95 V or GND	Switch ON or	25°C	3.6 V		6.8	9	μΑ
current	'+	VI = 1.85 V OI GIND	OFF	Full	3.0 v			10	μΑ

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### **ELECTRICAL CHARACTERISTICS FOR 2.5-V SUPPLY<sup>(1)</sup>**

 $V_{+} = 2.3 \text{ V}$  to 2.7 V,  $T_{A} = -40^{\circ}\text{C}$  to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST COND	DITIONS	TA	V <sub>+</sub>	MIN	TYP	MAX	UNIT
Analog Switch								<u> </u>	
Analog signal range	V <sub>COM</sub> , V <sub>NO</sub>					0		V <sub>+</sub>	V
ON-state resistance	r <sub>on</sub>	$V_{NO} = 1.8 \text{ V},$ $I_{COM} = -8 \text{ mA},$	Switch ON, See Figure 15	25°C Full	2.3 V		1.2	2.1	Ω
ON-state resistance match between channels	Δr <sub>on</sub>	V <sub>NO</sub> = 1.8 V, 0.8 V, I <sub>COM</sub> = -8 mA,	Switch ON, See Figure 15	25°C Full	2.3 V		0.045	0.15 0.15	Ω
ON-state resistance flatness	r <sub>on(flat)</sub>	V <sub>NO</sub> = 1.8 V, 0.8 V, I <sub>COM</sub> = -8 mA,	Switch ON, See Figure 15	25°C Full	2.3 V		0.4	0.6 0.6	Ω
NO OFF leakage current $ \begin{array}{c} V_{NO} = 2.3 \text{ V}, \\ V_{COM} = 0.5 \text{ V}, \\ \hline \\ I_{NO(PWROFF)} \end{array} \begin{array}{c} V_{NO} = 2.3 \text{ V}, \\ V_{COM} = 0.5 \text{ V}, \\ V_{COM} = 2.7 \text{ V}, \\ V_{COM} = 2.7 \text{ V} \text{ to } 0, \end{array} $	I <sub>NO(OFF)</sub>	$V_{COM} = 2.3 \text{ V},$ or $V_{NO} = 2.3 \text{ V},$		25°C	2.7 V	-8 -136	0.7	136	nA
	Full	0 V	<b>−</b> 5 <b>−</b> 10	0.02	5 10	μΑ			
COM OFF leakage current		V <sub>NO</sub> = 2.3 V,		25°C		-8	0.7	8	
	I <sub>COM(OFF)</sub>	$V_{COM} = 0.5 \text{ V},$ or $V_{NO} = 0.5 \text{ V},$ $V_{COM} = 2.3 \text{ V},$	Switch OFF, See Figure 16	Full	2.7 V	-136		136	nA
	1	$V_{NO} = 0 \text{ to } 2.7 \text{ V},$		25°C	0 V	<b>-</b> 5	0.02	5	μΑ
	ICOM(PWROFF)	$V_{COM} = 2.7 \text{ V to 0},$		Full	0 0	-10		10	μΑ
		$V_{NO} = 0.5 V,$		25°C		-2	0.3	2	
NO ON leakage current	I <sub>NO(ON)</sub>	$V_{COM}$ = Open, or $V_{NO}$ = 2.3 V, $V_{COM}$ = Open,	Switch ON, See Figure 17	Full	2.7 V	-15		15	nA
		$V_{COM} = 0.5 V,$		25°C		-2	0.3	2	
COM ON leakage current	I <sub>COM(ON)</sub>	$V_{NO} = Open,$ or $V_{COM} = 2.3 \text{ V},$ $V_{NO} = Open,$	Switch ON, See Figure 17	Full	2.7 V	-15		15	nA
Digital Control Inputs	s (IN1, IN2) <sup>(2)</sup>	,		•					
Input logic high	V <sub>IH</sub>			Full	2.7 V	1.05		5.5	V
Input logic low	V <sub>IL</sub>			Full	2.7 V	0		0.6	V
Input leakage current	I <sub>IH</sub> , I <sub>IL</sub>	V <sub>I</sub> = 1.95 V or GND		Full	2.7 V	-0.6		0.6	μΑ
Input resistance	r <sub>IN</sub>	V <sub>I</sub> = 1.95 V		Full	2.7 V		6		МΩ

 <sup>(1)</sup> The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum
 (2) All unused digital inputs of the device must be held at V<sub>+</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

### **ELECTRICAL CHARACTERISTICS FOR 2.5-V SUPPLY (continued)**

 $V_{+}$  = 2.3 V to 2.7 V,  $T_{A}$  = -40°C to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	YMBOL TEST CONDITIONS			V <sub>+</sub>	MIN	TYP	MAX	UNIT
Dynamic	•	•		•	· · · · · · · · · · · · · · · · · · ·				
				25°C	2.5 V	101	137	222	
Turn-on time	t <sub>ON</sub>	$V_{COM} = V_+,$ $R_L = 50 \Omega,$	C <sub>L</sub> = 35 pF, See Figure 19	Full	2.3 V to 2.7 V	68		288	ns
				25°C	2.5 V	148	264	333	
Turn-off time	t <sub>OFF</sub>	$V_{COM} = V_+,$ $R_L = 50 \Omega,$	C <sub>L</sub> = 35 pF, See Figure 19	Full	2.3 V to 2.7 V	197		367	ns
Charge injection	Q <sub>C</sub>	$V_{GEN} = 0,$ $R_{GEN} = 0,$			1.3		рС		
NO OFF capacitance	C <sub>NO(OFF)</sub>	$V_{NO} = V_{+}$ or GND, Switch OFF,	See Figure 18	25°C	2.5 V		19		pF
COM OFF capacitance	C <sub>COM(OFF)</sub>	$V_{NO} = V_{+}$ or GND, Switch OFF,	See Figure 18	25°C	2.5 V		17		pF
NO ON capacitance	C <sub>NO(ON)</sub>	$V_{NO} = V_{+}$ or GND, Switch ON,	See Figure 18	25°C	2.5 V		27.5		pF
COM ON capacitance	C <sub>COM(ON)</sub>	$V_{COM} = V_{+}$ or GND, Switch ON,	See Figure 18	25°C	2.5 V		27.5		pF
Digital input capacitance	Cı	$V_I = V_+ \text{ or GND},$	See Figure 18	25°C	2.5 V	2.5			pF
Power supply rejection ratio	PSRR	$ f = 10 \text{ kHz}, $ $ V_{COM} = 1 \text{ Vrms}, $ $ R_{L} = 50  \Omega, $	C <sub>L</sub> = 15 pF, See Figure 25	25°C	2.5 V	-84			dB
Bandwidth	BW	$R_L = 50 \Omega$ , Switch ON,	See Figure 20	25°C	2.5 V	260			MHz
OFF isolation	O <sub>ISO</sub>	$R_L = 50 \Omega$ , $f = 1 MHz$ ,	Switch OFF, See Figure 21	25°C	2.5 V		<b>–</b> 61		dB
Crosstalk	X <sub>TALK</sub>	$R_L$ = 50 Ω, Switch ON, f = 1 MHz, See Figure 22 25°C 2.5 V -99			dB				
Total harmonic distortion	THD	$R_L = 600 \Omega,$ $C_L = 15 pF,$				%			
Supply									
Positive supply current	I <sub>+</sub>	V <sub>I</sub> = 1.95 V or GND	Switch ON or OFF	25°C Full	2.7 V		6.6	9	μΑ

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### **ELECTRICAL CHARACTERISTICS FOR 1.8-V SUPPLY<sup>(1)</sup>**

 $V_{+} = 1.65 \text{ V}$  to 1.95 V,  $T_{A} = -40 ^{\circ}\text{C}$  to 85  $^{\circ}\text{C}$  (unless otherwise noted)

PARAMETER	R SYMBOL TEST CONDITIONS		TA	V <sub>+</sub>	MIN	TYP	MAX	UNIT	
Analog Switch									
Analog signal range	V <sub>COM</sub> , V <sub>NO</sub>								V
ON-state resistance	r <sub>on</sub>	$V_{NO} = 0.6 \text{ V}, 1.5 \text{ V},$ $I_{COM} = -2 \text{ mA},$	Switch ON, See Figure 15	25°C Full	1.65 V		1.6	4 5	Ω
ON-state resistance			0 % 1 0 1	25°C			0.045	0.2	
match between channels	$\Delta r_{ m on}$	$V_{NO} = 1.5 \text{ V},$ $I_{COM} = -2 \text{ mA},$	Switch ON, See Figure 15	Full	1.65 V			0.2	Ω
ON-state resistance	_	V <sub>NO</sub> = 0.6 V, 1.5 V,	Switch ON,	25°C	1.65 V		1.7	2.8	0
flatness	r <sub>on(flat)</sub>	$I_{COM} = -2 \text{ mA},$	See Figure 15	Full	1.65 V			3	Ω
		$V_{NO} = 0.3 V,$				-10	0.5	10	
NO OFF leakage current	I <sub>NO(OFF)</sub>	$V_{COM} = 1.65 \text{ V},$ or $V_{NO} = 1.65 \text{ V},$ $V_{COM} = 0.3 \text{ V},$	Switch OFF, See Figure 16	25°C	1.95 V	1.95 V30		30	nA
		$V_{NO} = 0 \text{ to } 1.95 \text{ V},$		E	0 V -	-5	0.02	5	μА
	I <sub>NO(PWROFF)</sub>	$V_{COM} = 1.95 \text{ V to } 0,$		Full	0 0	-10		10	
		$V_{NO} = 1.65 V,$		25°C		-10	0.5	10	
COM OFF leakage current	I <sub>COM(OFF)</sub>	$V_{COM} = 0.3 \text{ V},$ or $V_{NO} = 0.3 \text{ V},$ $V_{COM} = 1.65 \text{ V},$	Switch OFF, See Figure 16	Full	1.95 V	-30		30	nA
		$V_{NO} = 0 \text{ to } 1.95 \text{ V},$		25°C	0.1/	-5	0.02	5	μА
	I <sub>COM(PWROFF)</sub>	$V_{COM} = 1.95 \text{ V to } 0,$		Full	0 V	-10		10	
		$V_{NO} = 0.3 V$ ,		25°C		-2	0.2	2	
NO ON leakage current	N leakage $V_{COM} = Open,$ Switch ON,		Switch ON, See Figure 17	Full	1.95 V	-15		15	nA
	e current I <sub>COM(ON)</sub>	$V_{COM} = 0.3 \text{ V},$		25°C		-2	0.2	2	nA
COM ON leakage current		$V_{NO}$ = Open, or $V_{COM}$ = 1.65 V, $V_{NO}$ = Open,	Switch ON, See Figure 17	Full	1.95 V	-15		15	
Digital Control Inputs	(IN1, IN2) <sup>(2)</sup>			•					
Input logic high	V <sub>IH</sub>			Full	1.95 V	1.05		5.5	V
Input logic low	V <sub>IL</sub>			Full	1.95 V	0		0.6	V
Input leakage current	I <sub>IH</sub> , I <sub>IL</sub>	V <sub>I</sub> = 1.95 V or GND		Full	1.95 V	-0.6		0.6	μΑ
Input resistance	r <sub>IN</sub>	V <sub>I</sub> = 1.95 V		Full	1.95 V		6		ΜΩ

<sup>(1)</sup> The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum

Sub

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Product Folder Link(s): TS5A21366

<sup>(2)</sup> All unused digital inputs of the device must be held at V<sub>+</sub> or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

### **ELECTRICAL CHARACTERISTICS FOR 1.8-V SUPPLY (continued)**

 $V_{+}$  = 1.65 V to 1.95 V,  $T_{A}$  = -40°C to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS			V <sub>+</sub>	MIN	TYP	MAX	UNIT
Dynamic	•	•		•	· I				
				25°C	1.8 V	198	297	448	
Turn-on time	t <sub>ON</sub>	$V_{COM} = V_+,$ $R_L = 50 \Omega,$	C <sub>L</sub> = 35 pF, See Figure 19	Full	1.65 V to 1.95 V	136		620	ns
				25°C	1.8 V	225	308	430	
Turn-off time	t <sub>OFF</sub>	$V_{COM} = V_+,$ $R_L = 50 \Omega,$	C <sub>L</sub> = 35 pF, See Figure 19	Full	1.65 V to 1.95 V	204		514	ns
Charge injection	Q <sub>C</sub>	$V_{GEN} = 0,$ $R_{GEN} = 0,$			1.8 V		1.4		рС
NO OFF capacitance	C <sub>NO(OFF)</sub>	$V_{NO} = V_{+}$ or GND, Switch OFF,	See Figure 18	25°C	1.8 V		19		pF
COM OFF capacitance	C <sub>COM(OFF)</sub>	$V_{NO} = V_{+}$ or GND, Switch OFF,	See Figure 18	25°C	1.8 V		17		pF
NO ON capacitance	C <sub>NC(ON)</sub> , C <sub>NO(ON)</sub>	V <sub>NO</sub> = V <sub>+</sub> or GND, Switch ON,	See Figure 18	25°C	1.8 V		27.5		pF
COM ON capacitance	C <sub>COM(ON)</sub>	$V_{COM} = V_{+}$ or GND, Switch ON,	See Figure 18	25°C	1.8 V		27.5		pF
Digital input capacitance	Cı	$V_I = V_+ \text{ or GND},$	See Figure 18	25°C	1.8 V		2.5		pF
Power supply rejection ratio	PSRR	$ f = 10 \text{ kHz}, $ $ V_{COM} = 1 \text{ Vrms}, $ $ R_{L} = 50  \Omega, $	C <sub>L</sub> = 15 pF, See Figure 25	25°C	1.8 V		-78		dB
Bandwidth	BW	$R_L = 50 \Omega$ , Switch ON,	See Figure 20	25°C	1.8 V		260		MHz
OFF isolation	O <sub>ISO</sub>	$R_L = 50 \Omega$ , $f = 1 MHz$ ,	Switch OFF, See Figure 21	25°C	1.8 V		<b>–</b> 59		dB
Crosstalk	X <sub>TALK</sub>	$R_L = 50 \Omega$ , $f = 1 MHz$ ,	Switch ON, See Figure 22	25°C	1.8 V		-101		dB
Total harmonic distortion	THD	$ \begin{array}{llllllllllllllllllllllllllllllllllll$		1.8 V		0.001	_	%	
Supply									
Positive supply current	I <sub>+</sub>	V <sub>I</sub> = 1.95 V or GND	Switch ON or OFF	25°C Full	1.95 V		3.6	9	μΑ

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### PARAMETER DESCRIPTION

SYMBOL	DESCRIPTION
V <sub>COM</sub>	Voltage at COM
V <sub>NO</sub>	Voltage at NO
r <sub>on</sub>	Resistance between COM and NO ports when the channel is ON
r <sub>on(flat)</sub>	Difference between the maximum and minimum value of ron in a channel over the specified range of conditions
I <sub>NO(OFF)</sub>	Leakage current measured at the NO port, with the corresponding channel (NO to COM) in the OFF state
I <sub>NO(ON)</sub>	Leakage current measured at the NO port, with the corresponding channel (NO to COM) in the ON state and the output (COM) open
I <sub>COM(OFF)</sub>	Leakage current measured at the COM port, with the corresponding channel (COM to NO) in the OFF state
I <sub>COM(ON)</sub>	Leakage current measured at the COM port, with the corresponding channel (COM to NO) in the ON state and the output (NO) open
V <sub>IH</sub>	Minimum input voltage for logic high for the control input (IN)
V <sub>IL</sub>	Maximum input voltage for logic low for the control input (IN)
VI	Voltage at the control input (IN)
$I_{IH},\ I_{IL}$	Leakage current measured at the control input (IN)
t <sub>ON</sub>	Turn-on time for the switch. This parameter is measured under the specified range of conditions and by the propagation delay between the digital control (IN) signal and analog output (COM or NO) signal when the switch is turning ON.
t <sub>OFF</sub>	Turn-off time for the switch. This parameter is measured under the specified range of conditions and by the propagation delay between the digital control (IN) signal and analog output (COM or NO) signal when the switch is turning OFF.
$Q_C$	Charge injection is a measurement of unwanted signal coupling from the control (IN) input to the analog (NO or COM) output. This is measured in coulomb (C) and measured by the total charge induced due to switching of the control input. Charge injection, $Q_C = C_L \times \Delta V_{COM}$ , $C_L$ is the load capacitance and $\Delta V_{COM}$ is the change in analog output voltage.
C <sub>NO(OFF)</sub>	Capacitance at the NO port when the corresponding channel (NO to COM) is OFF
C <sub>NO(ON)</sub>	Capacitance at the NO port when the corresponding channel (NO to COM) is ON
C <sub>COM(OFF)</sub>	Capacitance at the COM port when the corresponding channel (COM to NO) is OFF
C <sub>COM(ON)</sub>	Capacitance at the COM port when the corresponding channel (COM to NO) is ON
C <sub>I</sub>	Capacitance of control input (IN)
O <sub>ISO</sub>	OFF isolation of the switch is a measurement of OFF-state switch impedance. This is measured in dB in a specific frequency, with the corresponding channel (NO to COM) in the OFF state.
X <sub>TALK</sub>	Crosstalk is a measurement of unwanted signal coupling from an ON channel to an OFF channel (NO1 to NO2). This is measured in a specific frequency and in dB.
BW	Bandwidth of the switch. This is the frequency in which the gain of an ON channel is -3 dB below the DC gain.
THD	Total harmonic distortion describes the signal distortion caused by the analog switch. This is defined as the ratio of root mean square (RMS) value of the second, third, and higher harmonic to the absolute magnitude of the fundamental harmonic.
I <sub>+</sub>	Static power-supply current with the control (IN) pin at V <sub>+</sub> or GND
$\Delta I_{+}$	This is the increase in $I_+$ for each control (IN) input that is at the specified voltage, rather than at $V_+$ or GND.



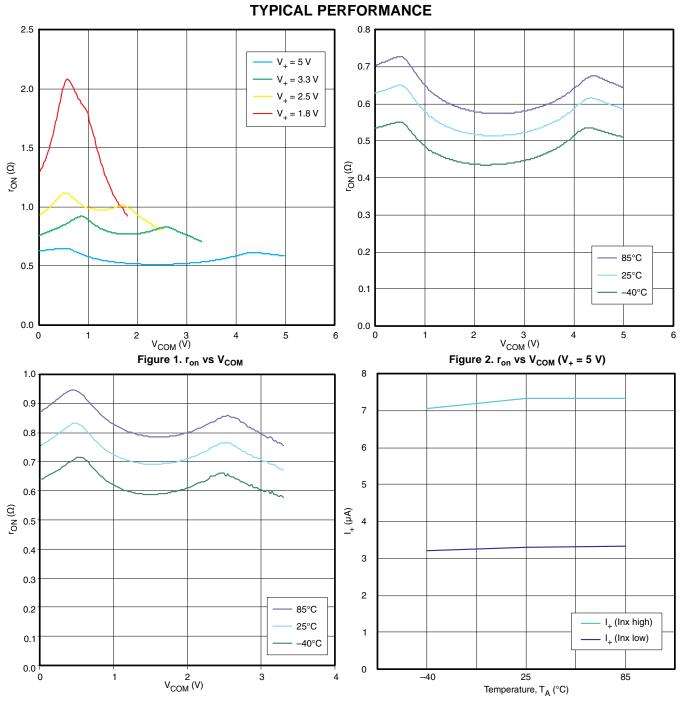


Figure 3.  $r_{on}$  vs  $V_{COM}$  ( $V_{+}$  = 3.3 V)

Figure 4. Power-Supply Current vs Temperature ( $V_{+} = 5 \text{ V}$ )



# **TYPICAL PERFORMANCE (continued)**

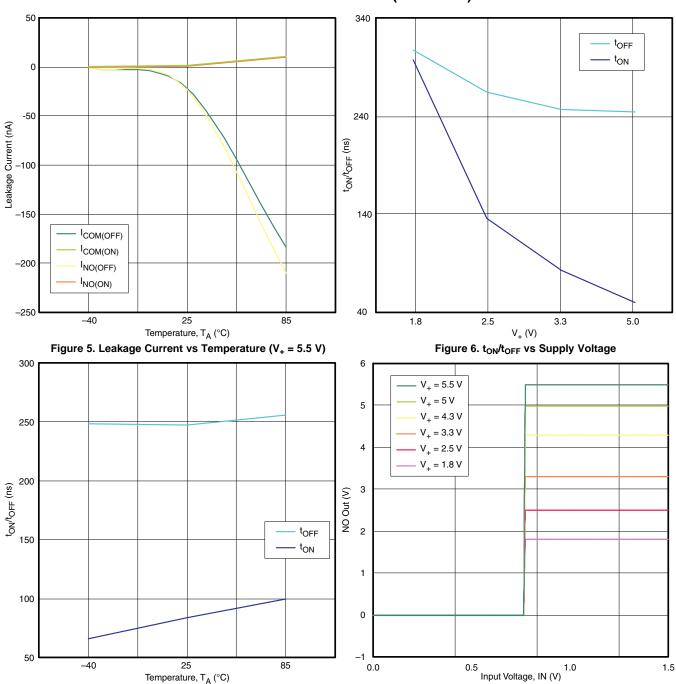


Figure 7.  $t_{ON}/t_{OFF}$  vs Temperature (V<sub>+</sub> = 3.3 V)

Figure 8. Input Voltage Thresholds



### **TYPICAL PERFORMANCE (continued)**

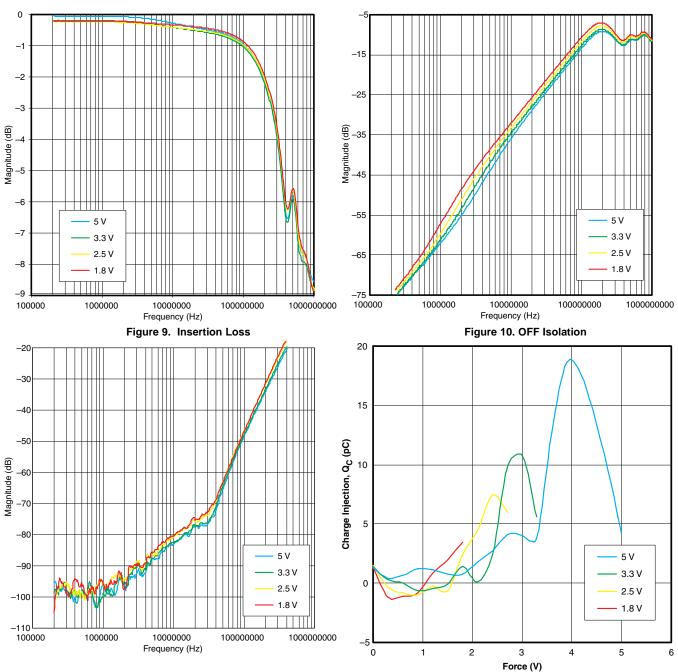


Figure 11. Crosstalk

Figure 12. Charge Injection ( $Q_C$ ) vs Bias Voltage



# **TYPICAL PERFORMANCE (continued)**

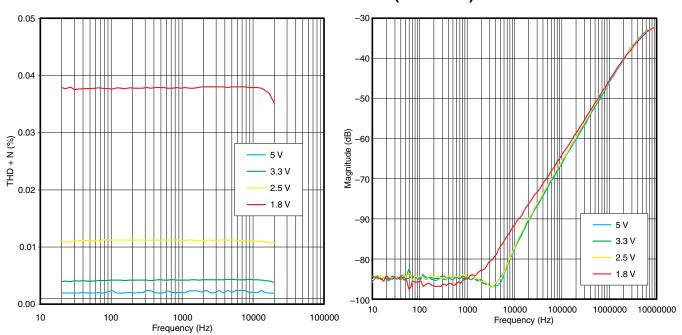


Figure 13. THD + N (%) vs Frequency

Figure 14. Power Supply Rejection Ratio (PSRR)



### PARAMETER MEASUREMENT INFORMATION

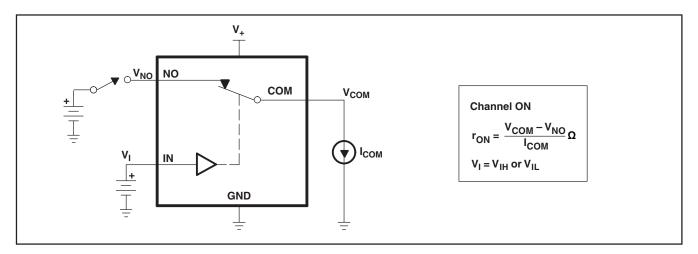


Figure 15. ON-State Resistance (ron)

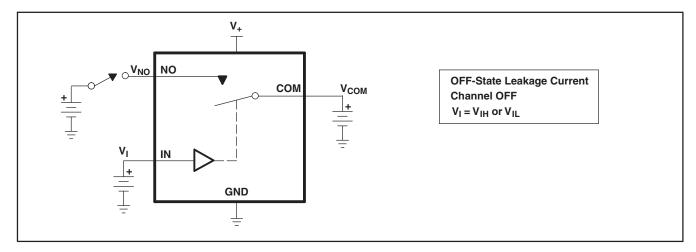


Figure 16. OFF-State Leakage Current ( $I_{COM(OFF)}$ ,  $I_{NO(OFF)}$ ,  $I_{COM(PWROFF)}$ ,  $I_{NOC(PWR(FF))}$ )

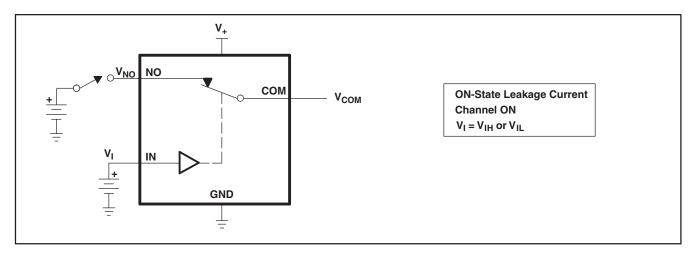


Figure 17. ON-State Leakage Current (I<sub>COM(ON)</sub>, I<sub>NO(ON)</sub>)

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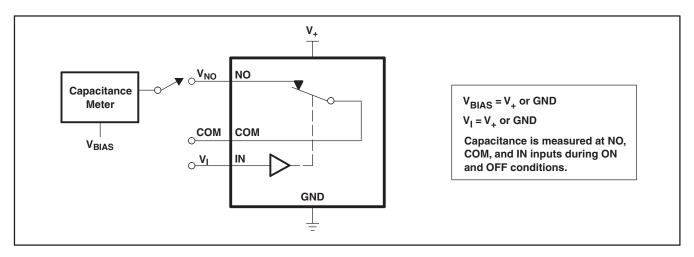
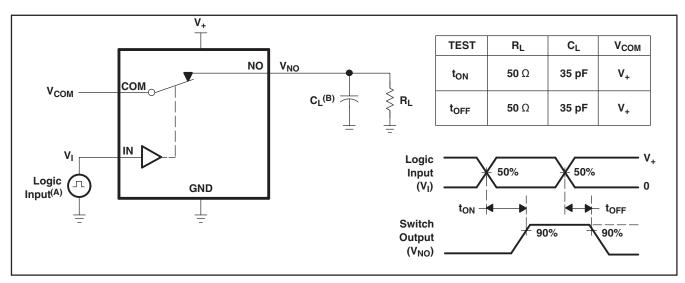


Figure 18. Capacitance (C<sub>I</sub>, C<sub>COM(OFF)</sub>, C<sub>COM(ON)</sub>, C<sub>NO(OFF)</sub>, C<sub>NO(ON)</sub>)



- A. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O = 50 \Omega$ ,  $t_f \leq$  5 ns,  $t_f \leq$  5 ns.
- B. C<sub>L</sub> includes probe and jig capacitance.

Figure 19. Turn-On (t<sub>ON</sub>) and Turn-Off Time (t<sub>OFF</sub>)



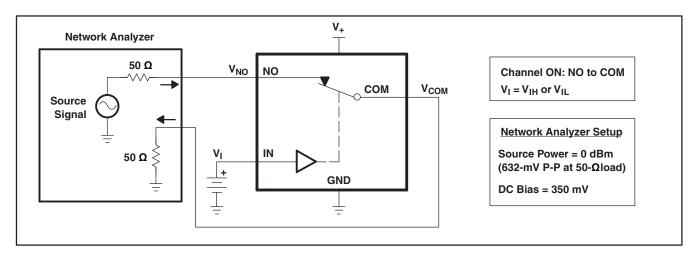


Figure 20. Bandwidth (BW)

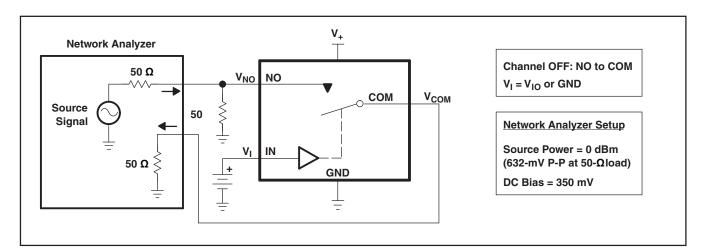


Figure 21. OFF Isolation (O<sub>ISO</sub>)

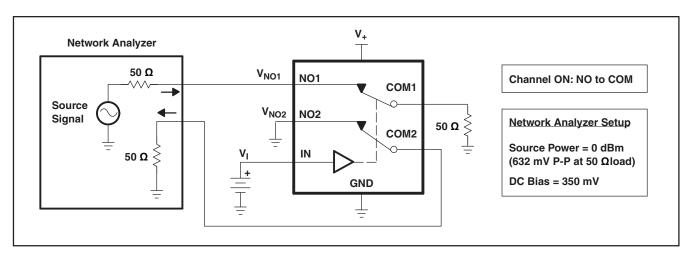
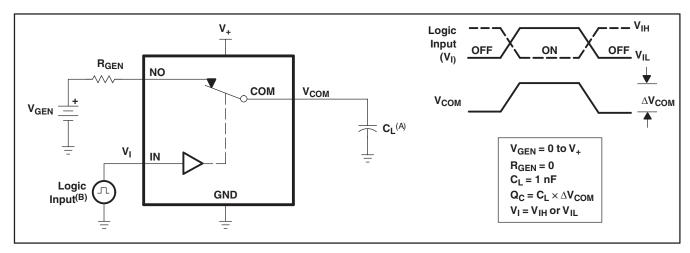


Figure 22. Crosstalk (X<sub>TALK</sub>)

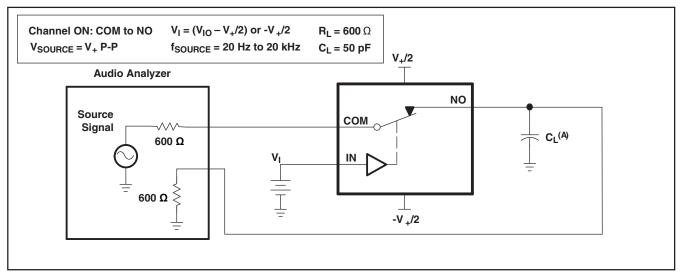
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- A. C<sub>L</sub> includes probe and jig capacitance.
- B. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z<sub>O</sub> = 50 Ω, t<sub>f</sub> ≤ 5 ns, t<sub>f</sub> ≤ 5 ns.

Figure 23. Charge Injection (Q<sub>C</sub>)



A. C<sub>L</sub> includes probe and jig capacitance.

Figure 24. Total Harmonic Distortion (THD)



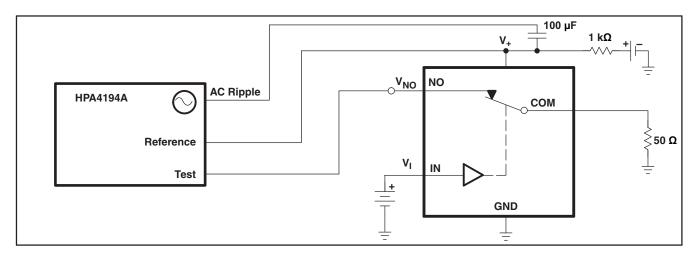


Figure 25. Power Supply Rejection Ratio (PSRR)



### **APPLICATION INFORMATION**

### Independent of V<sub>+</sub>, low-voltage GPIO-compatible control inputs

TS5A21366 integrates special control inputs with low threshold allowing the device to be controlled by 1.8-V signals. The thresholds are fixed and independent of the supply value ( $V_+$ ). The low threshold ( $V_{IH}$ ,  $V_{IL}$ ) of the control inputs (IN1, IN2) is achieved by use of an internal bias circuit. To avoid an increased quiescent current ( $I_+$ ) condition, proper power sequencing must be followed to ensure that the bias circuitry is powered up prior to applying voltage on the I/Os. The proper sequence is for the  $V_+$  pin to be brought up to  $V_+$  before the control inputs (IN1, IN2) are allowed to go to a high level.

# PACKAGE MATERIALS INFORMATION

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### TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

All differsions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TS5A21366DCUR	VSSOP	DCU	8	3000	180.0	9.0	2.05	3.3	1.0	4.0	8.0	Q3
TS5A21366DCUR	VSSOP	DCU	8	3000	180.0	8.4	2.25	3.35	1.05	4.0	8.0	Q3
TS5A21366DCURG4	VSSOP	DCU	8	3000	180.0	8.4	2.25	3.35	1.05	4.0	8.0	Q3
TS5A21366RSER	UQFN	RSE	8	3000	180.0	8.4	1.7	1.7	0.7	4.0	8.0	Q2

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\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TS5A21366DCUR	VSSOP	DCU	8	3000	182.0	182.0	20.0
TS5A21366DCUR	VSSOP	DCU	8	3000	202.0	201.0	28.0
TS5A21366DCURG4	VSSOP	DCU	8	3000	202.0	201.0	28.0
TS5A21366RSER	UQFN	RSE	8	3000	202.0	201.0	28.0

# DCU (R-PDSO-G8)

# PLASTIC SMALL-OUTLINE PACKAGE (DIE DOWN)



NOTES:

- : A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
  - D. Falls within JEDEC MO-187 variation CA.



DCU (S-PDSO-G8)

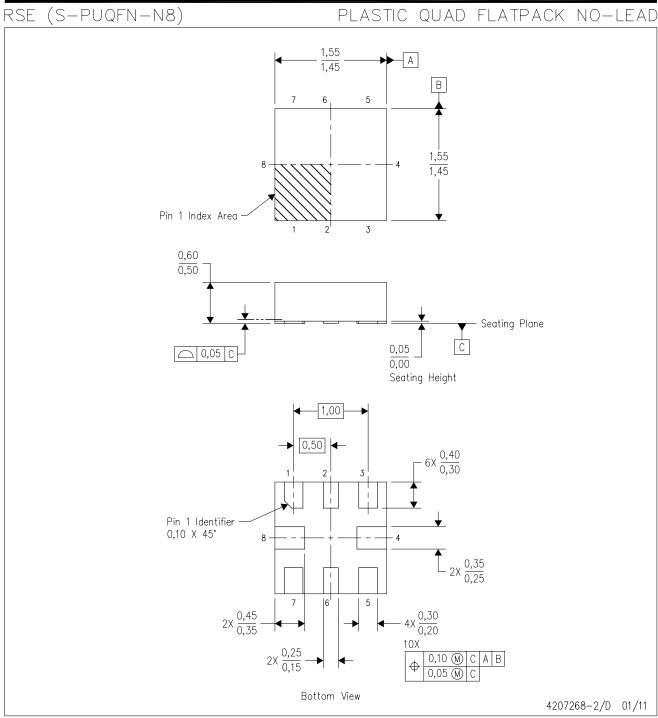
PLASTIC SMALL OUTLINE PACKAGE (DIE DOWN)



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.





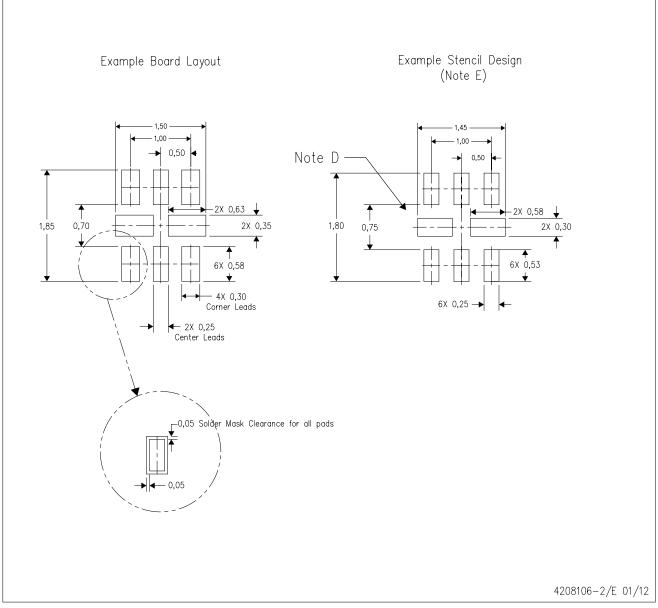
NOTES: All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
  C. QFN (Quad Flatpack No-Lead) package configuration.
  D. This package complies to JEDEC MO-288 variation UECD.



# RSE (S-PUQFN-N8)

### PLASTIC QUAD FLATPACK NO-LEAD



- NOTES: A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Publication IPC-7351 is recommended for alternate designs.
  - D. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.
  - E. Maximum stencil thickness 0,127 mm (5 mils). All linear dimensions are in millimeters.
  - F. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
  - G. Side aperture dimensions over-print land for acceptable area ratio > 0.66. Customer may reduce side aperture dimensions if stencil manufacturing process allows for sufficient release at smaller opening.



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